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<ul> <li>Parallel-to-Serial, Serial-to-Parallel Conversions</li> </ul>	DW OR N PACKAGE (TOP VIEW)
Left or Right Shifts	
• Parallel Synchronous Loading	SR SER 1 20 S0
Direct Overriding Clear	$Q_A \parallel 2$ 19 $\parallel S1$
• Temporary Data Latching Capability	Q <sub>B</sub> U 3 18U A GND I 4 17 I B
Flow-Through Architecture to Optimize	$GND$ $\begin{bmatrix} 5 \\ 5 \end{bmatrix}$ 16 $\begin{bmatrix} V_{CC} \end{bmatrix}$
PCB Layout	
• Center-Pin V <sub>CC</sub> and GND Configurations to	GND [] 7 14 [] C
Minimize High-Speed Switching Noise	$Q_C \begin{bmatrix} 8 & 13 \end{bmatrix} D$
● EPIC <sup>™</sup> (Enhanced-Performance Implanted	$Q_D \downarrow 9$ 12 CLR
CMOS) 1-µm Process	
500-mA Typical Latch-Up Immunity at	

- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages, and Standard Plastic 300-mil DIPs

#### description

This bidirectional shift register features parallel outputs, right-shift and left-shift serial inputs, operating-mode-control inputs, and a direct overriding clear line. The register has four distinct modes of operation:

Parallel (broadside) load Shift right (in the direction  $Q_A$  toward  $Q_D$ ) Shift left (in the direction  $Q_D$  toward  $Q_A$ ) Inhibit clocking (do nothing).

Synchronous parallel loading is accomplished by applying the 4 bits of data and taking both mode control inputs, S0 and S1, high. The data are loaded into the associated flip-flops and appear at the outputs after the positive transition of the clock input. During loading, serial data flow is inhibited.

Shift right is accomplished synchronously with the rising edge of the clock pulse when S0 is high and S1 is low. Serial data for this mode is entered at the shift-right data input. When S0 is low and S1 is high, data shifts left synchronously, and new data is entered at the shift-left serial inputs. Clocking of the flip-flop is inhibited when both mode control inputs are low.

The 74AC11194 is characterized for operation from – 40°C to 85°C.

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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	Function Table												
	INPUTS								OUTI	PUTS			
CLEAR	MO	DE	CLOCK	SEF	RIAL		PARA	LLEL		0.	0-	0.0	0-
CLEAR	S1	S0	CLUCK	LEFT	RIGHT	Α	В	С	D	QA	QB	QC	QD
L	Х	Х	Х	Х	Х	Х	Х	Х	Х	L	L	L	L
н	Х	Х	L	Х	Х	Х	Х	Х	Х	Q <sub>A0</sub>	Q <sub>B0</sub>	Q <sub>C0</sub>	Q <sub>D0</sub>
н	н	Н	↑	Х	Х	а	b	С	d	а	b	С	d
н	L	Н	↑	Х	Н	Х	Х	Х	Х	н	Q <sub>An</sub>	Q <sub>Bn</sub>	Q <sub>Cn</sub>
н	L	Н	↑	Х	L	Х	Х	Х	Х	L	Q <sub>An</sub>	Q <sub>Bn</sub>	Q <sub>Cn</sub>
н	н	L	↑	н	Х	Х	Х	Х	Х	Q <sub>Bn</sub>	QCn	Q <sub>Dn</sub>	Н
н	н	L	↑	L	Х	Х	Х	Х	Х	Q <sub>Bn</sub>	Q <sub>Cn</sub>	Q <sub>Dn</sub>	L
н	L	L	Х	Х	Х	Х	Х	Х	Х	Q <sub>AO</sub>	QBO	QCO	Q <sub>DO</sub>

H = high level (steady state)

L = low level (steady state)

X = irrelevant (any input, including transitions)

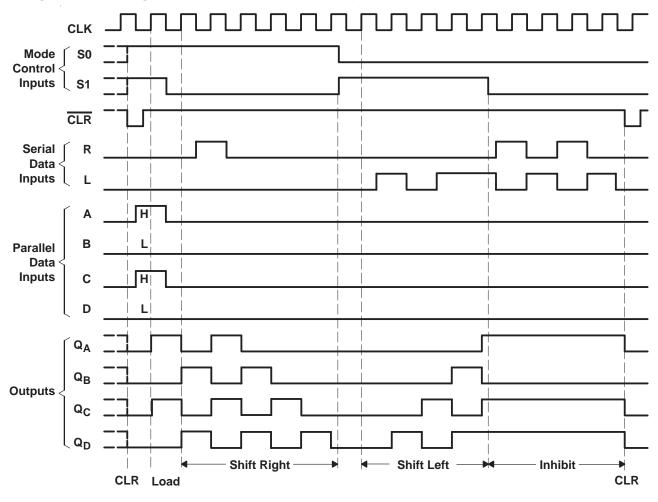
 $\uparrow$  = transition from low to high level

a,b,c,d = the level of steady-state input at inputs A, B, C, or D, respectively.

 $Q_{AO}$ ,  $Q_{BO}$ ,  $Q_{CO}$ ,  $Q_{DO}$  = the level of  $Q_A$ ,  $Q_B$ ,  $Q_C$ , or  $Q_D$ , respectively, before the indicated steady-state input conditions were established.

 $Q_{An}$ ,  $Q_{Bn}$ ,  $Q_{Cn}$ ,  $Q_{Dn}$  = the level of  $Q_A$ ,  $Q_B$ ,  $Q_C$ , or  $Q_D$  respectively, before the most-recent  $\uparrow$  transition of the clock.

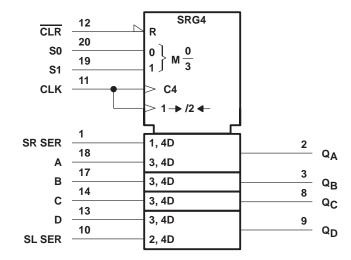
#### timing clear, load, right-shift, inhibit, and clear sequences



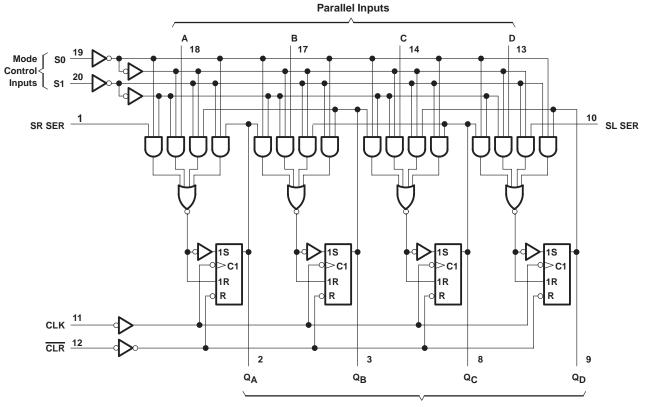


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## logic symbol<sup>†</sup>



logic diagram (positive logic)



**Parallel Outputs** 



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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V <sub>CC</sub>	–0.5 V to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)	$-0.5 \text{ V}$ to V <sub>CC</sub> + 0.5 V
Output voltage range, V <sub>O</sub> (see Note 1)	$-0.5 \text{ V}$ to V <sub>CC</sub> + 0.5 V
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0 or V <sub>I</sub> > V <sub>CC</sub> )	$\dots \dots \pm 20 \text{ mA}$
Output clamp current, $I_{OK}$ ( $V_O < 0$ or $V_O > V_{CC}$ )	
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$	$\dots \dots \pm 50 \text{ mA}$
Continuous current through V <sub>CC</sub> or GND pins	
Storage temperature range	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

			MIN	NOM	MAX	UNIT
VCC	Supply voltage		3	5	5.5	V
		$V_{CC} = 3 V$	2.1			
VIH	High-level input voltage	$V_{CC} = 4.5 V$	3.15			V
		V <sub>CC</sub> = 5.5 V	3.85			
		V <sub>CC</sub> = 3 V			0.9	
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 4.5 V			1.35	V
		V <sub>CC</sub> = 5.5 V			1.65	
		V <sub>CC</sub> = 3 V			-4	
ЮН	High-level output current	$V_{CC} = 4.5 V$			-24	mA
		V <sub>CC</sub> = 5.5 V			-24	
		V <sub>CC</sub> = 3 V			12	
IOL	Low-level output current	$V_{CC} = 4.5 V$			24	mA
		V <sub>CC</sub> = 5.5 V			24	
$\vee_{I}$	Input voltage		0		VCC	V
VO	Output voltage		0		VCC	V
$\Delta t/\Delta v$	Input transition rise or fall rate		0		10	ns/V
TA	Operating free-air temperature		- 40		85	°C

#### recommended operating conditions



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PARAMETER	TEST CONDITIONS	Vac	T,	λ = 25°C	;	MIN	MAX	UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	WIIIN	WAA	UNIT
		3 V	2.9			2.9		
	I <sub>OH</sub> =  – 50 μA	4.5 V	4.4			4.4		
		5.5 V	5.4			5.4		
VOH	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		V
	IOH = – 24 mA	4.5 V	3.94			3.8		
	IOH = -24  mA		4.94			4.8		
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V				3.85		
		3 V			0.1		0.1	
	I <sub>OL</sub> = 50 μA	4.5 V			0.1		0.1	
		5.5 V			0.1		0.1	
VOL	I <sub>OL</sub> = 12 mA	3 V			0.36		0.44	V
	le. 24 mA	4.5 V			0.36		0.44	
	I <sub>OL</sub> = 24 mA	5.5 V			0.36		0.44	
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V					1.65	
Ц	$V_I = V_{CC} \text{ or } GND$	5.5 V			± 0.1		±1	μA
ICC	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	5.5 V			8		80	μA
Ci	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		4				рF

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

<sup>†</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

# timing requirements over recommended operating free-air temperature range, V<sub>CC</sub> = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 1)

	PARAMETER					MIN MAX		UNIT	
							WIAA	UNIT	
<sup>f</sup> clock	Clock frequency			0	90	0	90	MHz	
		CLK high		5.5		5.5			
tw	Pulse duration	CLK low		5.5		5.5		ns	
		CLR low		4.5		4.5			
•	Setup time before CLK ↑	Select		5		5			
t <sub>su</sub>	Setup time before CEK 1	Data		4		4		ns	
+.	Hold time after CLK 1	Select		1.5		1.5		20	
th			0.5		0.5		ns		
t	Recovery time			1		1		ns	



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# timing requirements over recommended operating free-air temperature range, V<sub>CC</sub> = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

	PARAMI	T <sub>A</sub> =	T <sub>A</sub> = 25°C		MAX	UNIT	
	FARAMI	MIN	MAX	MIN	WAA	UNIT	
fclock	Clock frequency		0	100	0	100	MHz
		CLK high	5		5		
tw	Pulse duration	CLK low	5		5		ns
		CLR low	4.5		4.5		
	Satur time before CLK	Select	4		4		
t <sub>su</sub>	Setup time before CLK $\uparrow$	Data	2.5		2.5		ns
<b>4</b> .	Hold time after CLK ↑	Select	1.5		1.5		
t <sub>h</sub>	Hold lime alter CLK	1		1		ns	
t	Recovery time		1		1		ns

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	Т	ן = 25°C	;	MIN	MAX	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	WIIIN	IVIAA	UNIT
f <sub>max</sub>	-		90	120		90		MHz
<sup>t</sup> PHL	CLK	ΔηγΟ	1	5.8	8.4	1	9.5	ns
<sup>t</sup> PLH	CLK	Any Q	1	6.6	8.9	1	10.2	115
<sup>t</sup> PHL	CLR	Any Q	1.7	7.1	9.5	1.7	10.7	ns

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

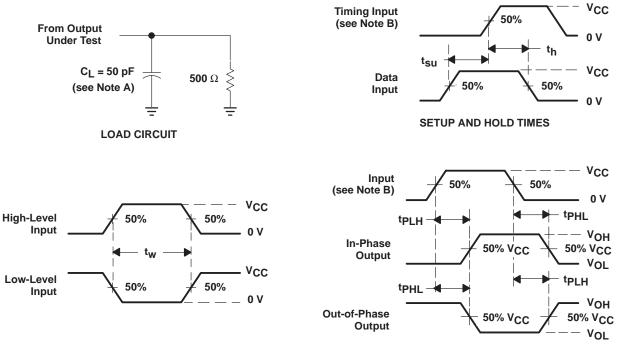
PARAMETER	FROM	то	Т	ן = 25°C	;	MIN	MAX	UNIT
FARAWETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	IVIIIN	IVIAA	UNIT
f <sub>max</sub>			100	130		100		MHz
<sup>t</sup> PHL	CLK	Δηγ.Ο	0.8	3.9	6.2	0.8	6.8	ns
<sup>t</sup> PLH	CLK	Any Q	1.1	4.4	6.6	1.1	7.7	115
<sup>t</sup> PHL	CLR	Any Q	1.5	4.6	7	1.5	7.8	ns

## operating characteristics, V<sub>CC</sub> = 5 V, T<sub>A</sub> = $25^{\circ}$ C

	PARAMETER	TEST CONDITIONS	TYP	UNIT
Cpd	Power dissipation capacitance	$C_L = 50 \text{ pF}, \qquad f = 1 \text{ MHz}$	66	pF



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### PARAMETER MEASUREMENT INFORMATION

PULSE DURATION



- NOTES: A. CL includes probe and jig capacitance.
  - B. Input pulses are supplied by generators having the following characteristics:  $PRR \le 10 \text{ MHz}$ ,  $Z_0 = 50 \Omega$ ,  $t_r = 3 \text{ ns}$ ,  $t_f = 3 \text{ ns}$ . For testing  $f_{max}$  and pulse duration:  $t_r = 1$  to 3 ns,  $t_f = 1$  to 3 ns.
  - C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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